

1. General description

Ultrafast power diode in a SOT428 (DPAK) surface-mountable plastic package.

2. Features and benefits

- High thermal cycling performance
- Low switching losses
- Low thermal resistance
- Soft recovery minimizes power-consuming oscillations
- Surface-mountable package

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- High frequency switched-mode power supplies

4. Quick reference data

Table 1. Qui	ck reference data					
Symbol	Parameter	Conditions	М	in Typ	Max	Unit
V _R	reverse voltage	DC	-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} ≤ 132 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	-	5	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	-	60	A
		t _p = 8.3 ms; T _{j(init)} = 25 °C; sine-wave pulse	-	-	66	A
Static chara	acteristics				·	
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.12	1.3	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.97	1.11	V
Dynamic ch	naracteristics			·		
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/µs; T _j = 25 °C; <u>Fig. 7</u>	-	30	50	ns

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5. Pinning information

Table 2. F	inning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	<u>[]</u>	К-Қ-А
2	К	cathode[1]		001aaa020
3	A	anode		
mb	К	cathode	DPAK (SOT428)	

[1] It is not possible to connect to pin 2 of the SOT428 package

6. Ordering information

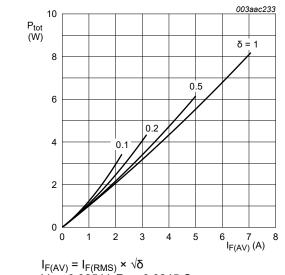
Table 3. Ordering inform	mation					
Type number	Package	ickage				
	Name	Description	Version			
BYV25D-600	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428			

7. Limiting values

Table 4. Limiting values

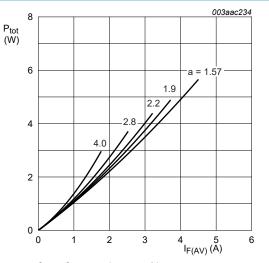
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 132 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	5	A
I _{FRM}	repetitive peak forward current	δ = 0.5 ; T _{mb} ≤ 132 °C; square-wave pulse	-	10	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	60	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	66	A
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



 $V_{o} = 0.985 \text{ V}; \text{ R}_{s} = 0.0245 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



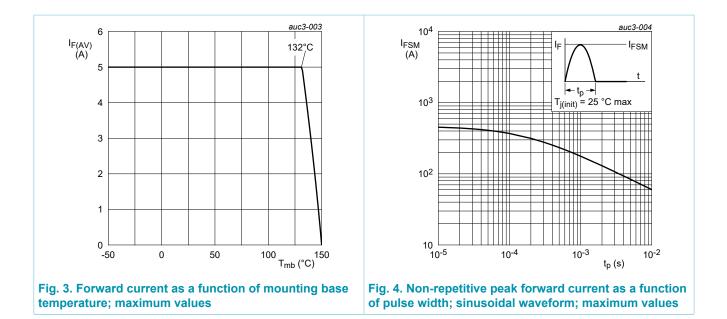
a = form factor = I $_{F(RMS)}$ / I $_{F(AV)}$ V $_o$ = 0.985 V; R $_s$ = 0.0245 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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BYV25D-600

Ultrafast power diode



BYV25D-600

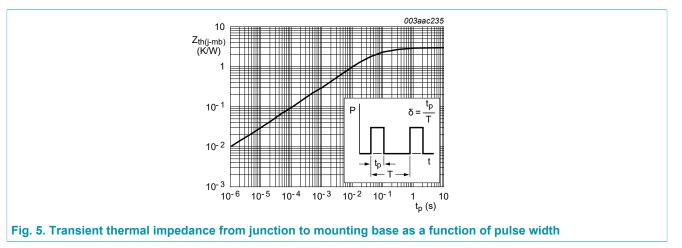


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8. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	3	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air		[1]	-	50	-	K/W

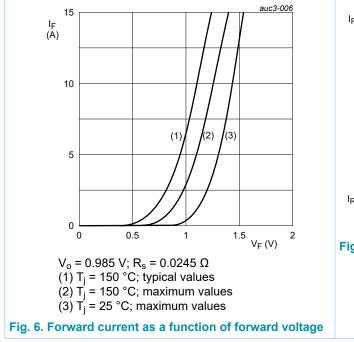
[1] device mounted on an FR4 PCB, single-sided copper, tin plated and standard footprint



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9. Characteristics

Table 6. Cha	racteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	·				
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; <u>Fig. 6</u>	-	1.12	1.3	V
		I _F = 5 A; T _j = 150 °C; <u>Fig. 6</u>	-	0.97	1.11	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	2	50	μA
		V _R = 600 V; T _j = 100 °C	-	0.1	0.35	mA
Dynamic ch	naracteristics				1	
t _{rr}	reverse recovery time	I _F = 1 A; V _R = 30 V; dI _F /dt = 100 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	30	50	ns
I _{RM}	peak reverse recovery current	I _F = 10 A; V _R = 30 V; dI _F /dt = 50 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	2.4	4	A
Q _r	recovered charge	I _F = 2 A; V _R = 30 V; dI _F /dt = 20 A/μs; T _j = 25 °C; <u>Fig. 7</u>	-	30	50	nC
V _{FR}	forward recovery voltage	I _F = 10 A; dI _F /dt = 10 A/μs; T _j = 25 °C	-	3.2	-	V



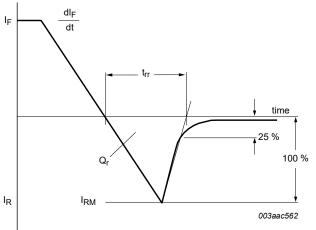


Fig. 7. Reverse recovery definitions; ramp recovery

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10. Package outline

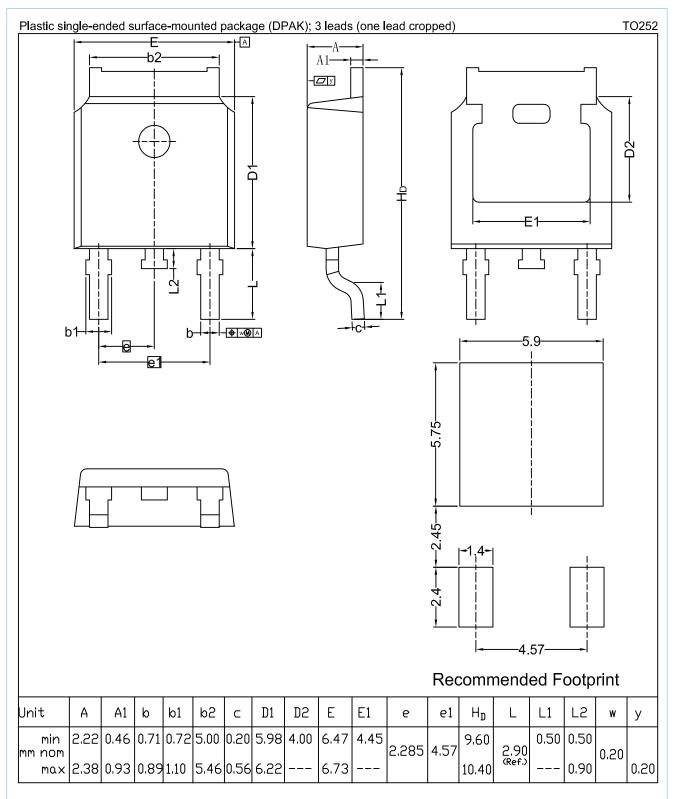


Fig. 8. Package outline DPAK (SOT428)

BYV25D-600

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11. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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